

View Online at <https://aerobasegroup.com/nsn/5961-01-223-9424>

**Inclosure Material:**

Ceramic

**Overall Length:**

0.785 inches

**Overall Height:**

0.200 inches

**Overall Width:**

0.320 inches

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Terminal

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor

**Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current all transistor

**Power Rating Per Characteristic:**

1.9 watts small-signal input power, common-collector absolute all transistor

**Transfer Ratio:**

75.0 static forward current transfer ratio, common-emitter all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction

**Special Features:**

All transistor junction pattern arrangement: npn

**Test Data Document:**

96214-2692212 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:**

14 uninsulated wire lead

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A110a0